

Bias Resistor Transistor

NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

LDTC144ELT1G

● **Applications**

Inverter, Interface, Driver

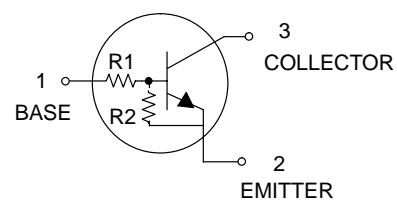
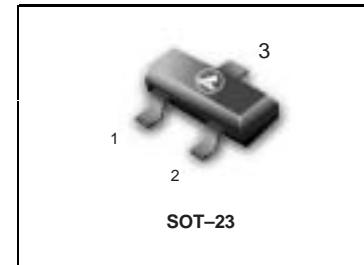
● **Features**

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors.
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input, and parasitic effects are almost completely eliminated.
- 3) Only the on / off conditions need to be set for operation, making the device design easy.
- 4) Higher mounting densities can be achieved.

- We declare that the material of product compliance with RoHS requirements.

● **Absolute maximum ratings (Ta=25°C)**

Parameter	Symbol	Limits	Unit
Supply voltage	V _{cc}	50	V
Input voltage	V _i	-10 to +40	V
Output current	I _o	30	mA
	I _{C(Max.)}	100	
Power dissipation	P _D	200	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C



DEVICE MARKING AND RESISTOR VALUES

Device	Marking	R1 (K)	R2 (K)	Shipping
LDTC144ELT1G	N5	47	47	3000/Tape & Reel
LDTC144ELT1G	N5	47	47	10000/Tape & Reel

● **External characteristics (Unit: mm)**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _{i(off)}	—	—	0.5	V	V _{cc} =5V, I _o =100μA
	V _{i(on)}	3	—	—		V _o =0.3V, I _o =2mA
Output voltage	V _{o(on)}	—	0.1	0.3	V	I _o /I _l =10mA/0.5mA
Input current	I _i	—	—	0.18	mA	V _i =5V
Output current	I _{o(off)}	—	—	0.5	μA	V _{cc} =50V, V _i =0V
DC current gain	G _i	68	—	—	—	V _o =5V, I _o =5mA
Input resistance	R _i	32.9	47	61.1	kΩ	—
Resistance ratio	R ₂ /R ₁	0.8	1	1.2	—	—
Transition frequency	f _T *	—	250	—	MHz	V _{ce} =10V, I _e =-5mA, f=100MHz

* Characteristics of built-in transistor

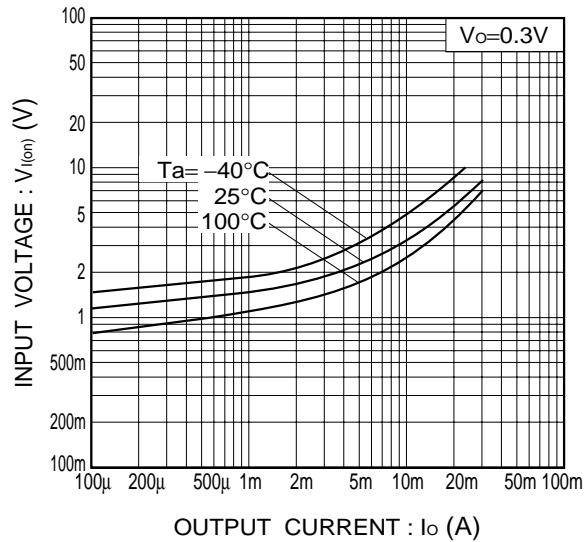
LDTC144ELT1G
●Electrical characteristics curves


Fig.1 Input voltage vs. output current
(ON characteristics)

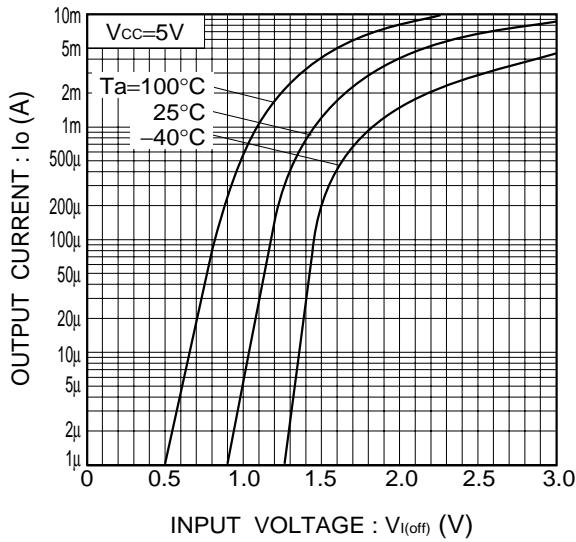


Fig.2 Output current vs. input voltage
(OFF characteristics)

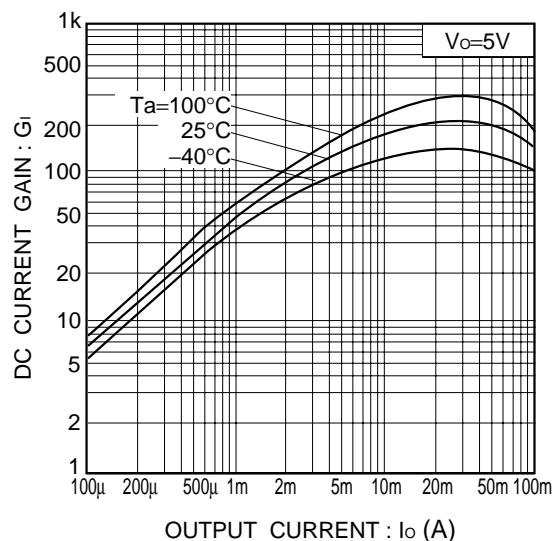


Fig.3 DC current gain vs. output current

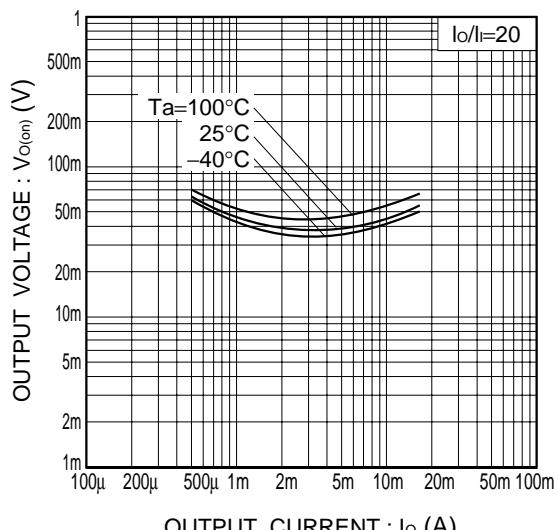
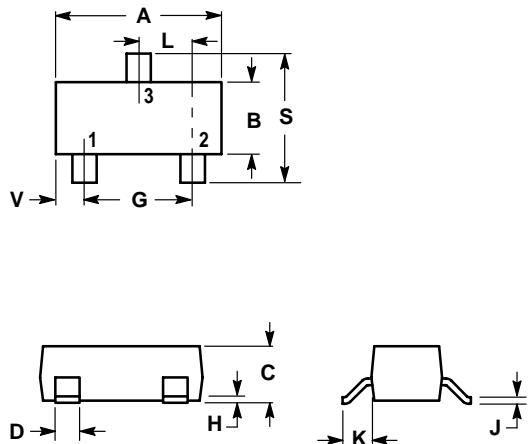


Fig.4 Output voltage vs. output current

LDTC144ELT1G
SOT-23
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

